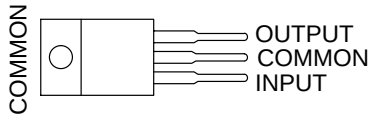
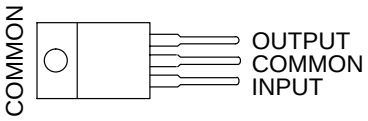
SLVS056J – MAY 1976 – REVISED MAY 2003

- **3-Terminal Regulators**
- **Output Current up to 1.5 A**
- **Internal Thermal-Overload Protection**
- **High Power-Dissipation Capability**
- **Internal Short-Circuit Current Limiting**
- **Output Transistor Safe-Area Compensation**

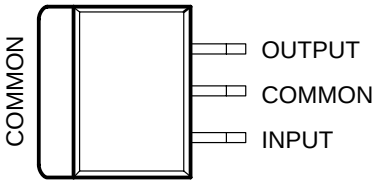
KC (TO-220) PACKAGE
(TOP VIEW)



KCS (TO-220) PACKAGE
(TOP VIEW)



KTE PACKAGE
(TOP VIEW)



description/ordering information

This series of fixed-voltage integrated-circuit voltage regulators is designed for a wide range of applications. These applications include on-card regulation for elimination of noise and distribution problems associated with single-point regulation. Each of these regulators can deliver up to 1.5 A of output current. The internal current-limiting and thermal-shutdown features of these regulators essentially make them immune to overload. In addition to use as fixed-voltage regulators, these devices can be used with external components to obtain adjustable output voltages and currents, and also can be used as the power-pass element in precision regulators.

ORDERING INFORMATION

T_J	$V_{O(NOM)}$ (V)	PACKAGE†		ORDERABLE PART NUMBER	TOP-SIDE MARKING
0°C to 125°C	5	POWER-FLEX (KTE)	Reel of 2000	μA7805CKTER	μA7805C
		TO-220 (KC)	Tube of 50	μA7805CKC	μA7805C
		TO-220, short shoulder (KCS)	Tube of 20	μA7805CKCS	
	8	POWER-FLEX (KTE)	Reel of 2000	μA7808CKTER	μA7808C
		TO-220 (KC)	Tube of 50	μA7808CKC	μA7808C
		TO-220, short shoulder (KCS)	Tube of 20	μA7808CKCS	
	10	POWER-FLEX (KTE)	Reel of 2000	μA7810CKTER	μA7810C
		TO-220 (KC)	Tube of 50	μA7810CKC	μA7810C
	12	POWER-FLEX (KTE)	Reel of 2000	μA7812CKTER	μA7812C
		TO-220 (KC)	Tube of 50	μA7812CKC	μA7812C
		TO-220, short shoulder (KCS)	Tube of 20	μA7812CKCS	
	15	POWER-FLEX (KTE)	Reel of 2000	μA7815CKTER	μA7815C
		TO-220 (KC)	Tube of 50	μA7815CKC	μA7815C
		TO-220, short shoulder (KCS)	Tube of 20	μA7815CKCS	
	24	POWER-FLEX (KTE)	Reel of 2000	μA7824CKTER	μA7824C
		TO-220 (KC)	Tube of 50	μA7824CKC	μA7824C

† Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

recommended operating conditions

			MIN	MAX	UNIT
V_I	Input voltage	μA7805C	7	25	V
		μA7808C	10.5	25	
		μA7810C	12.5	28	
		μA7812C	14.5	30	
		μA7815C	17.5	30	
		μA7824C	27	38	
I_O	Output current			1.5	A
T_J	Operating virtual junction temperature	μA7800C series	0	125	°C

electrical characteristics at specified virtual junction temperature, V_I = 10 V, I_O = 500 mA (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_J†	μA7805C			UNIT
			MIN	TYP	MAX	
Output voltage	I_O = 5 mA to 1 A, V_I = 7 V to 20 V, $P_D \le$ 15 W	25°C	4.8	5	5.2	V
		0°C to 125°C	4.75		5.25	
Input voltage regulation	V_I = 7 V to 25 V	25°C		3	100	mV
	V_I = 8 V to 12 V			1	50	
Ripple rejection	V_I = 8 V to 18 V, f = 120 Hz	0°C to 125°C	62	78		dB
Output voltage regulation	I_O = 5 mA to 1.5 A	25°C		15	100	mV
	I_O = 250 mA to 750 mA			5	50	
Output resistance	f = 1 kHz	0°C to 125°C		0.017		Ω
Temperature coefficient of output voltage	I_O = 5 mA	0°C to 125°C		–1.1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz	25°C		40		μV
Dropout voltage	I_O = 1 A	25°C		2		V
Bias current		25°C		4.2	8	mA
Bias current change	V_I = 7 V to 25 V	0°C to 125°C			1.3	mA
	I_O = 5 mA to 1 A				0.5	
Short-circuit output current		25°C		750		mA
Peak output current		25°C		2.2		A

† Pulse-testing techniques maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output.

electrical characteristics at specified virtual junction temperature, V_I = 14 V, I_O = 500 mA (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_J†	μA7808C			UNIT
			MIN	TYP	MAX	
Output voltage	I_O = 5 mA to 1 A, V_I = 10.5 V to 23 V, $P_D \le 15$ W	25°C	7.7	8	8.3	V
		0°C to 125°C	7.6		8.4	
Input voltage regulation	V_I = 10.5 V to 25 V	25°C		6	160	mV
	V_I = 11 V to 17 V			2	80	
Ripple rejection	V_I = 11.5 V to 21.5 V, f = 120 Hz	0°C to 125°C	55	72		dB
Output voltage regulation	I_O = 5 mA to 1.5 A	25°C		12	160	mV
	I_O = 250 mA to 750 mA			4	80	
Output resistance	f = 1 kHz	0°C to 125°C		0.016		Ω
Temperature coefficient of output voltage	I_O = 5 mA	0°C to 125°C		–0.8		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz	25°C		52		μV
Dropout voltage	I_O = 1 A	25°C		2		V
Bias current		25°C		4.3	8	mA
Bias current change	V_I = 10.5 V to 25 V	0°C to 125°C			1	mA
	I_O = 5 mA to 1 A				0.5	
Short-circuit output current		25°C		450		mA
Peak output current		25°C		2.2		A

† Pulse-testing techniques maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output.

electrical characteristics at specified virtual junction temperature, V_I = 17 V, I_O = 500 mA (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_J†	μA7810C			UNIT
			MIN	TYP	MAX	
Output voltage	I_O = 5 mA to 1 A, V_I = 12.5 V to 25 V, $P_D \le 15$ W	25°C	9.6	10	10.4	V
		0°C to 125°C	9.5	10	10.5	
Input voltage regulation	V_I = 12.5 V to 28 V	25°C		7	200	mV
	V_I = 14 V to 20 V			2	100	
Ripple rejection	V_I = 13 V to 23 V, f = 120 Hz	0°C to 125°C	55	71		dB
Output voltage regulation	I_O = 5 mA to 1.5 A	25°C		12	200	mV
	I_O = 250 mA to 750 mA			4	100	
Output resistance	f = 1 kHz	0°C to 125°C		0.018		Ω
Temperature coefficient of output voltage	I_O = 5 mA	0°C to 125°C		–1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz	25°C		70		μV
Dropout voltage	I_O = 1 A	25°C		2		V
Bias current		25°C		4.3	8	mA
Bias current change	V_I = 12.5 V to 28 V	0°C to 125°C			1	mA
	I_O = 5 mA to 1 A				0.5	
Short-circuit output current		25°C		400		mA
Peak output current		25°C		2.2		A

† Pulse-testing techniques maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output.

electrical characteristics at specified virtual junction temperature, V_I = 19 V, I_O = 500 mA (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_J†	μA7812C			UNIT
			MIN	TYP	MAX	
Output voltage	I_O = 5 mA to 1 A, V_I = 14.5 V to 27 V, $P_D \le 15$ W	25°C	11.5	12	12.5	V
		0°C to 125°C	11.4		12.6	
Input voltage regulation	V_I = 14.5 V to 30 V	25°C		10	240	mV
	V_I = 16 V to 22 V			3	120	
Ripple rejection	V_I = 15 V to 25 V, f = 120 Hz	0°C to 125°C	55	71		dB
Output voltage regulation	I_O = 5 mA to 1.5 A	25°C		12	240	mV
	I_O = 250 mA to 750 mA			4	120	
Output resistance	f = 1 kHz	0°C to 125°C		0.018		Ω
Temperature coefficient of output voltage	I_O = 5 mA	0°C to 125°C		–1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz	25°C		75		μV
Dropout voltage	I_O = 1 A	25°C		2		V
Bias current		25°C		4.3	8	mA
Bias current change	V_I = 14.5 V to 30 V	0°C to 125°C			1	mA
	I_O = 5 mA to 1 A				0.5	
Short-circuit output current		25°C		350		mA
Peak output current		25°C		2.2		A

† Pulse-testing techniques maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output.

electrical characteristics at specified virtual junction temperature, V_I = 23 V, I_O = 500 mA (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_J†	μA7815C			UNIT
			MIN	TYP	MAX	
Output voltage	I_O = 5 mA to 1 A, V_I = 17.5 V to 30 V, $P_D \le 15$ W	25°C	14.4	15	15.6	V
		0°C to 125°C	14.25		15.75	
Input voltage regulation	V_I = 17.5 V to 30 V	25°C		11	300	mV
	V_I = 20 V to 26 V			3	150	
Ripple rejection	V_I = 18.5 V to 28.5 V, f = 120 Hz	0°C to 125°C	54	70		dB
Output voltage regulation	I_O = 5 mA to 1.5 A	25°C		12	300	mV
	I_O = 250 mA to 750 mA			4	150	
Output resistance	f = 1 kHz	0°C to 125°C		0.019		Ω
Temperature coefficient of output voltage	I_O = 5 mA	0°C to 125°C		–1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz	25°C		90		μV
Dropout voltage	I_O = 1 A	25°C		2		V
Bias current		25°C		4.4	8	mA
Bias current change	V_I = 17.5 V to 30 V	0°C to 125°C			1	mA
	I_O = 5 mA to 1 A				0.5	
Short-circuit output current		25°C		230		mA
Peak output current		25°C		2.1		A

† Pulse-testing techniques maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output.

electrical characteristics at specified virtual junction temperature, V_I = 33 V, I_O = 500 mA (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_J†	μA7824C			UNIT
			MIN	TYP	MAX	
Output voltage	I_O = 5 mA to 1 A, V_I = 27 V to 38 V, $P_D \le 15$ W	25°C	23	24	25	V
		0°C to 125°C	22.8		25.2	
Input voltage regulation	V_I = 27 V to 38 V	25°C		18	480	mV
	V_I = 30 V to 36 V			6	240	
Ripple rejection	V_I = 28 V to 38 V, f = 120 Hz	0°C to 125°C	50	66		dB
Output voltage regulation	I_O = 5 mA to 1.5 A	25°C		12	480	mV
	I_O = 250 mA to 750 mA			4	240	
Output resistance	f = 1 kHz	0°C to 125°C		0.028		Ω
Temperature coefficient of output voltage	I_O = 5 mA	0°C to 125°C		–1.5		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz	25°C		170		μV
Dropout voltage	I_O = 1 A	25°C		2		V
Bias current		25°C		4.6	8	mA
Bias current change	V_I = 27 V to 38 V	0°C to 125°C			1	mA
	I_O = 5 mA to 1 A				0.5	
Short-circuit output current		25°C		150		mA
Peak output current		25°C		2.1		A

† Pulse-testing techniques maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output.